



**This technology is currently not available for licensing**

Tech ID: 31967

**ADDITIONAL TECHNOLOGIES BY THESE INVENTORS**

- ▶ [A Structure For Increasing Mobility In A High-Electron-Mobility Transistor](#)
- ▶ [\(In,Ga,Al\)N Optoelectronic Devices with Thicker Active Layers for Improved Performance](#)
- ▶ [GaN-based Vertical Metal Oxide Semiconductor and Junction Field Effect Transistors](#)
- ▶ [Iii-N Transistor With Stepped Cap Layers](#)
- ▶ [III-N Based Material Structures and Circuit Modules Based on Strain Management](#)

